# NSN 5961-01-023-2829

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Inclosure Material:

Plastic

**Overall Length:** 

0.643 inches

## **Overall Height:**

0.135 inches

**Overall Width:** 

0.505 inches

## **Mounting Facility Quantity:**

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

90.0 watts small-signal input power, common-collector absolute

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnp

### **Terminal Type And Quantity:**

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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